7th RD50 Workshop

Monday, 14 November 2005

Defect Engineering (DE) - 40-S2-A01 (13:15 - 15:35)

time	[id] title	presenter
13:15	[18] The issue of the doping disuniformity in p-type MCz Si detectors	MARA BRUZZI
	[22] Results on Technotest sub-project: long term annealing of CZ Si detectors irradiated by 24 GeV/c protons	ELENA VERBITSKAYA
13:55	[17] An annealing study on 23 GeV proton irradiated n-type MCz pad detectors	MOLL, Michael
14:15	[21] Initial data on the DRIVE approach: results and analysis	ZHENG LI
14:35	[19] Discussion: Defect Engineering	ECKHART FRETWURST AND GREGOR KRAMBERGER
15:05	[20] Coffee Break	